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IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of: **Yoshiaki TANIDA et al.**

Group Art Unit: **2822**

Serial No.: **10/614,227**

Examiner: **Monica Lewis**

Filed: **July 8, 2003**

Confirmation No.: **6141**

For: **SEMICONDUCTOR DEVICE HAVING LOW INTERFACE STATE
DENSITY AND METHOD FOR FABRICATING THE SAME
(as herein amended)**

Attorney Docket Number: **030823**

Customer Number: **38834**

RESPONSE

Commissioner for Patents
P.O. Box 1450
Alexandria, Virginia 22313-1450

November 12, 2004

Sir:

In response to the Office Action dated August 11, 2004, Applicant amends the above-identified application as follows and submits the following remarks.

Amendments to the Specification begin on page 2 of this paper.

Amendments to the Claims begin on page 3 of this paper.

Remarks/Arguments begin on page 8 of this paper.

Amendments to the Drawings are reflected in the Replacement Figure 5 attached hereto.